

ZXT13P20DE6

20V PNP LOW SATURATION SWITCHING TRANSISTOR IN SOT26

Features

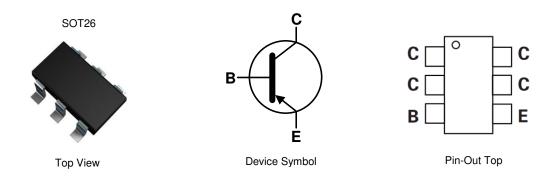
- BV_{CEO} > -20V
- I_C = -3.5A Continuous Collector Current
- I_{CM} = -10A Peak Pulse Current
- $R_{CE(sat)} = 75m\Omega$ for a Low Equivalent On-Resistance
- Low Saturation Voltage of <-130mV max @ -1A
- hFE Characterized up to -10A for High Current Gain Hold-Up
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.015 grams (Approximate)

Applications

- DC-DC Converters
- Power Management Functions
- Power Switches
- Motor Control



Ordering Information (Notes 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXT13P20DE6TA	P20D	7	8	3,000

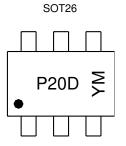
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



 $\begin{array}{l} \mathsf{P20D}=\mathsf{Product Type Marking Code}\\ \mathsf{YM}=\mathsf{Date Code Marking}\\ \mathsf{Y} \mbox{ or }\overline{\mathsf{Y}}=\mathsf{Year} \mbox{ (ex: C}=2015)\\ \mathsf{M} \mbox{ or }\overline{\mathsf{M}}=\mathsf{Month} \mbox{ (ex: 9}=\mathsf{September)} \end{array}$

Date Code Key

Build Boudd	1.09													
Year	201	5	2016	;	2017	2018	2019	2020	202	1 20	22 2	2023	2024	2025
Code	C		D		E	F	G	Н			J	K	L	М
Mont	h	Ja	n	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	•	1		2	3	4	5	6	7	8	9	0	N	D

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Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-25	V
Collector-Emitter Voltage	V _{CEO}	-20	V
Emitter-Base Voltage	V _{EBO}	-7.5	V
Base Current	Ι _Β	-500	mA
Continuous Collector Current	lc	-3.5	A
Peak Pulse Collector Current	I _{СМ}	-10	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	P	1.1 8.8	W	
Linear Derating Factor	(Note 6)	P _D	1.7 13.6	mW/°C	
Thermal Resistance, Junction to Ambient	(Note 5) (Note 6)	R _{θJA}	113 73	°C/W	
Thermal Resistance, Junction to Lead	(Note 7)	R _{θJL}	18.61		
Operating and Storage Temperature Range		TJ, T _{STG}	-55 to +150	°C	

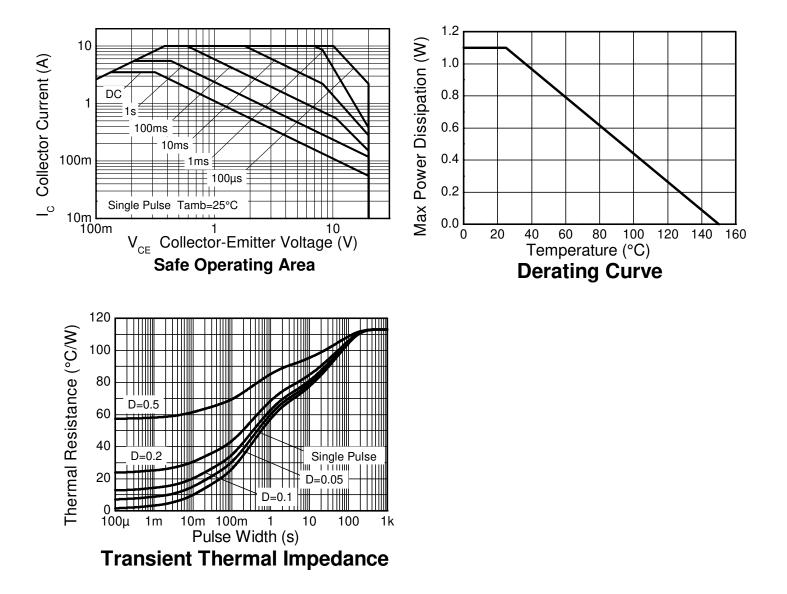
ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with collector leads on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air 6. Some as Note 5, except the device is measured at t ≤ 5 seconds.
7. Thermal resistance from junction to solder-point (at the end of the collector leads).
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

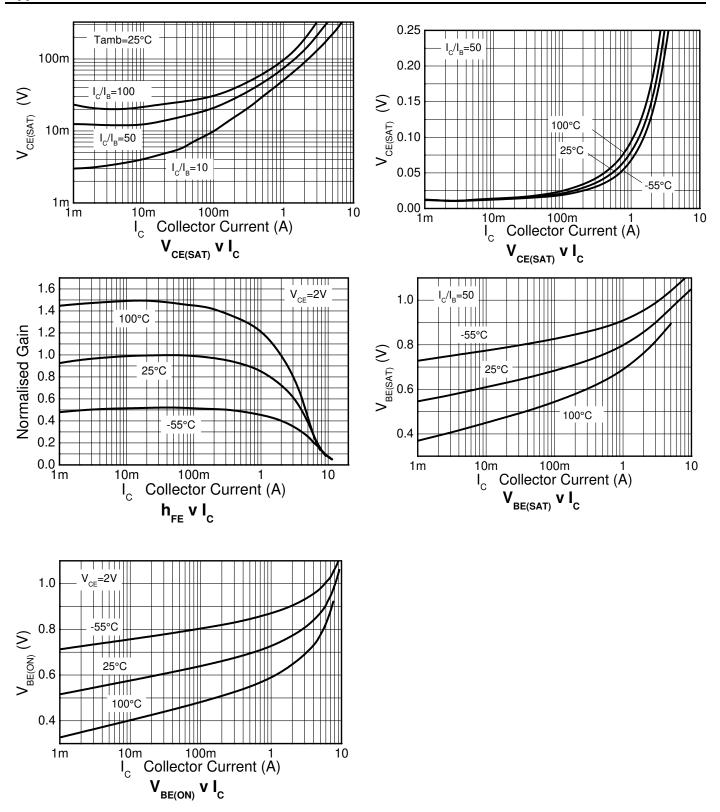
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS			- 71-			
Collector-Base Breakdown Voltage	BV _{CBO}	-25	-55		V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-20	-50	_	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7.5	-8.5	_	V	I _E = -100μA
Collector-Base Cut-Off Current	I _{CBO}	_	_	-100	nA	$V_{CB} = -20V$
Emitter Cut-Off Current	I _{EBO}	_	_	-100	nA	$V_{EB} = -6V$
Collector-Emitter Cut-Off Current	I _{CES}		_	-100	nA	V _{CES} = -20V
ON CHARACTERISTICS (Note 9)						
		300	500			$I_{C} = -10mA, V_{CE} = -2V$
DC Current Gain	h	300	450	900		$I_{C} = -1A, V_{CE} = -2V$
	h _{FE}	150	250			$I_{C} = -3.5A, V_{CE} = -2V$
		10	—			$I_{C} = -10A, V_{CE} = -2V$
		_	-10	-15		$I_{C} = -100 \text{mA}, I_{B} = -10 \text{mA}$
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	-100	-130	mV	$I_{C} = -1A, I_{B} = -10mA$
		—	-165	-250		I _C = -3.5A, I _B = -350mA
Base-Emitter Saturation Voltage	V _{BE(sat)}	_	_	-1.1	V	I _C = -3.5A, I _B = -350mA
Base-Emitter Turn-On Voltage	V _{BE(on)}	_	_	-0.9	V	I _C = -3.5A, V _{CE} = -2V
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f _T		90		MHz	$V_{CE} = -10V, I_{C} = -50mA, f = 50MHz$
Output Capacitance	Cobo		62		pF	$V_{CB} = -10V$, f = 1MHz
Turn-On Time	t _(on)		95		ns	$V_{CC} = -10V, I_{C} = -2A$
Turn-Off Time	t _(off)	_	395	_	ns	$I_{B1} = I_{B2} = -40 \text{mA}$

Note: 9. Measured under pulsed conditions; pulse width \leq 300µs, duty cycle \leq 2%.



ZXT13P20DE6

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Тур

0.05

1.10

0.75

0.38

0.15

3.00

0.95

1.90

2.80

1.60

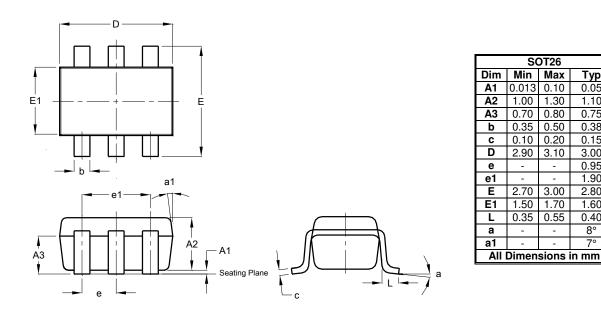
0.40

8°

7°

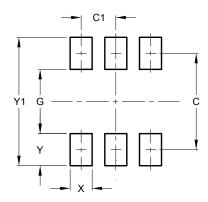
Package Outline

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20



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